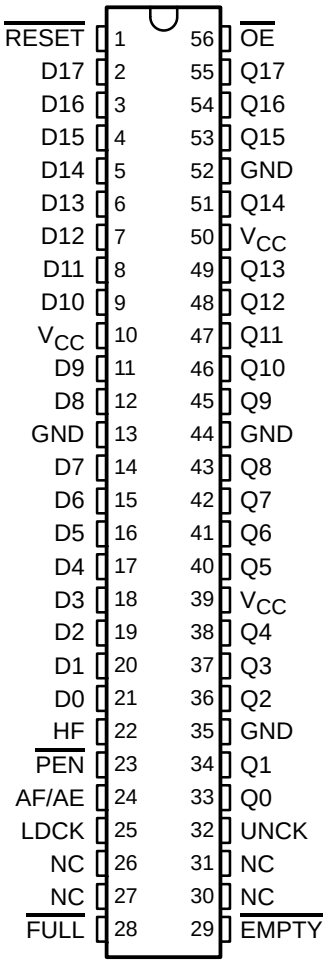
- **Operates at 3-V to 3.6-V V_{CC}**
- **Load Clock and Unload Clock Can Be Asynchronous or Coincident**
- **Low-Power Advanced CMOS Technology**
- **Full, Empty, and Half-Full Flags**
- **Programmable Almost-Full/Almost-Empty Flag**
- **Fast Access Times of 18 ns With a 50-pF Load and All Data Outputs Switching Simultaneously**
- **Data Rates From 0 to 40 MHz**
- **3-State Outputs**
- **Pin Compatible With SN74ACT7814**
- **Packaged in Shrink Small-Outline 300-mil Package (DL) Using 25-mil Center-to-Center Spacing**

DL PACKAGE
(TOP VIEW)



description

A FIFO memory is a storage device that allows data to be written into and read from its array at independent data rates. The SN74ALVC7814 is an 18-bit FIFO with high speed and fast access times. Data is processed at rates up to 40 MHz with access times of 18 ns in a bit-parallel format. This memory is designed for 3-V to 3.6-V V_{CC} operation.

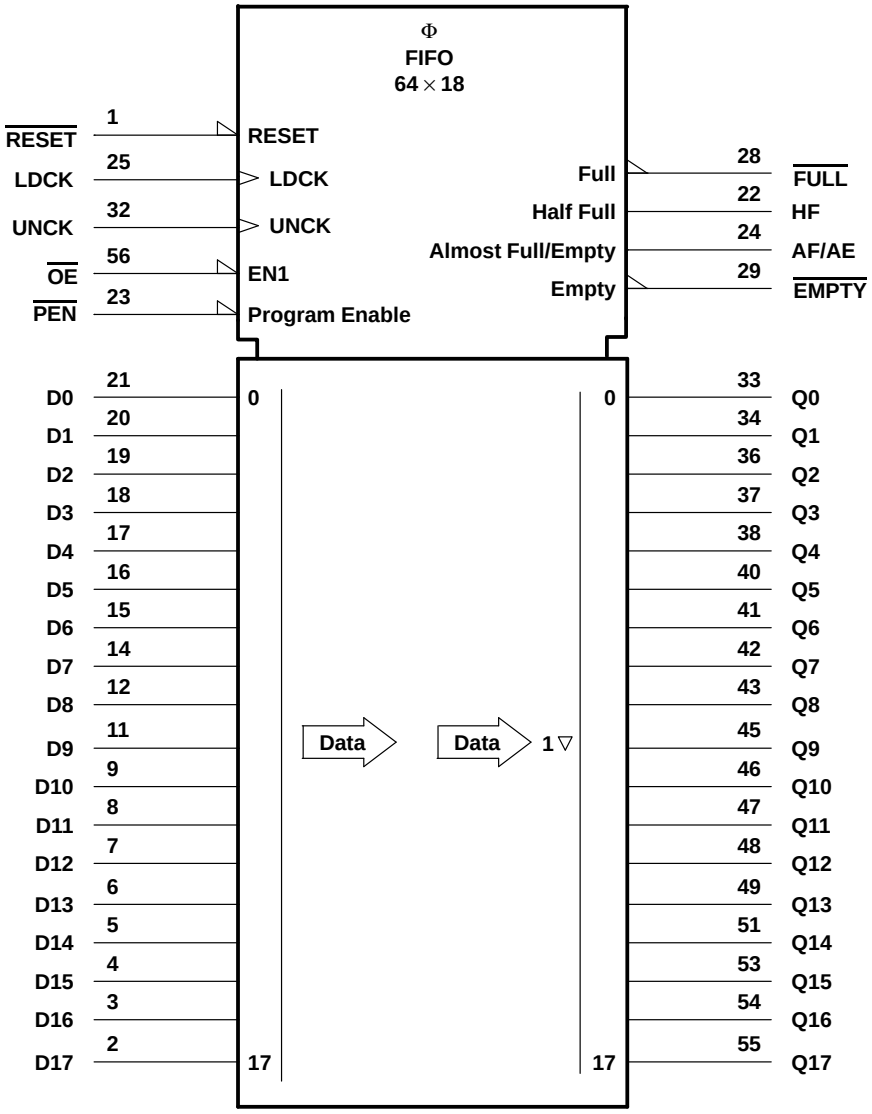
Data is written into memory on a low-to-high transition of the load clock (LDCK) and is read out on a low-to-high transition of the unload clock (UNCK). The memory is full when the number of words clocked in exceeds the number of words clocked out by 64. When the memory is full, LDCK has no effect on the data residing in memory. When the memory is empty, UNCK has no effect.

Status of the FIFO memory is monitored by the full ($\overline{FULL}$), empty ($\overline{EMPTY}$), half-full (HF), and almost-full/almost-empty (AF/AE) flags. The $\overline{FULL}$ output is low when the memory is full and high when the memory is not full. The $\overline{EMPTY}$ output is low when the memory is empty and high when it is not empty. The HF output is high when the FIFO contains 32 or more words and is low when it contains 31 or fewer words. The AF/AE status flag is a programmable flag. The first one or two low-to-high transitions of LDCK after reset are used to program the almost-empty offset value (X) and the almost-full offset value (Y) if program enable ($\overline{PEN}$) is low. The AF/AE flag is high when the FIFO contains X or fewer words or (64 minus Y) or more words. The AF/AE flag is low when the FIFO contains between (X plus 1) and (63 minus Y) words.

A low level on the reset ($\overline{RESET}$) resets the internal stack pointers and sets $\overline{FULL}$ high, AF/AE high, HF low, and $\overline{EMPTY}$ low. The Q outputs are not reset to any specific logic level. The FIFO must be reset upon power up. The first word loaded into empty memory causes $\overline{EMPTY}$ to go high and the data to appear on the Q outputs. The data outputs are in the high-impedance state when the output-enable ($\overline{OE}$) is high.

PRODUCT PREVIEW

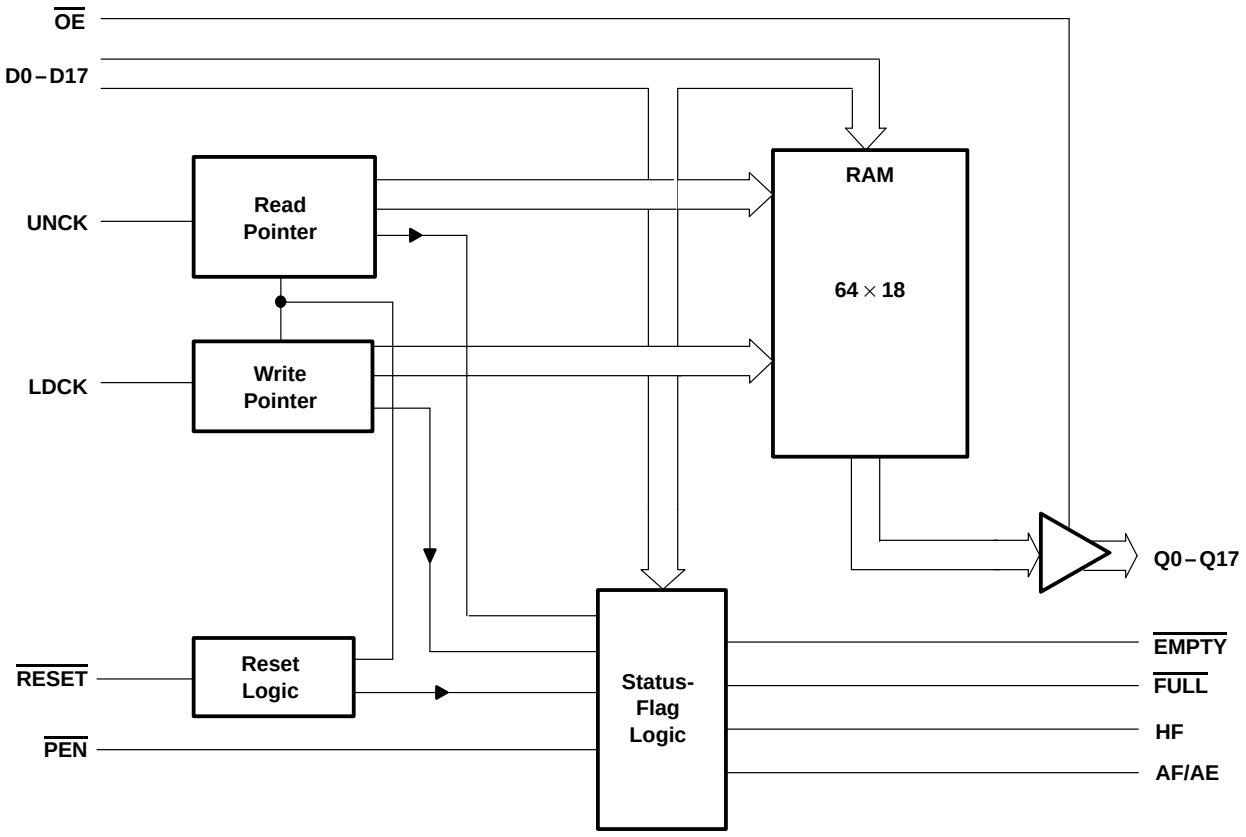
logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

PRODUCT PREVIEW

functional block diagram



Terminal Functions

TERMINAL NAME	TERMINAL NO.	I/O	DESCRIPTION
AF/AE	24	O	Almost full/almost empty flag. Depth offset values can be programmed for AF/AE, or the default value of 8 can be used for both the almost empty offset (X) and the almost full offset (Y). AF/AE is high when memory contains X or fewer words or (64 – Y) or more words. AF/AE is high after reset.
D0–D17	21–14, 12–11, 9–2	I	18-bit data input port
$\overline{\text{EMPTY}}$	29	O	Empty flag. $\overline{\text{EMPTY}}$ is low when the FIFO is empty. A FIFO reset also causes $\overline{\text{EMPTY}}$ to go low.
$\overline{\text{FULL}}$	28	O	Full flag. $\overline{\text{FULL}}$ is low when the FIFO is full. A FIFO reset causes $\overline{\text{FULL}}$ to go high.
HF	22	O	Half-full flag. HF is high when the FIFO memory contains 32 or more words. HF is low after reset.
LDCK	25	I	Load clock. Data is written to the FIFO on the rising edge of LDCK when $\overline{\text{FULL}}$ is high.
$\overline{\text{OE}}$	56	I	Output enable. When $\overline{\text{OE}}$ is high, the data outputs are in the high-impedance state.
$\overline{\text{PEN}}$	23	I	Program enable. After reset and before the first word is written to the FIFO, the binary value on D0–D4 is latched as an AF/AE offset value when $\overline{\text{PEN}}$ is low and WRTCLK is high.
Q0–Q17	33–34, 36–38, 40–43, 45–49, 51, 53–55	O	18-bit data output port
$\overline{\text{RESET}}$	1	I	Reset. A low level on $\overline{\text{RESET}}$ resets the FIFO and drives AF/AE and $\overline{\text{FULL}}$ high and HF and $\overline{\text{EMPTY}}$ low.
UNCK	32	I	Unload clock. Data is read from the FIFO on the rising edge of UNCK when $\overline{\text{EMPTY}}$ is high.

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PRODUCT PREVIEW

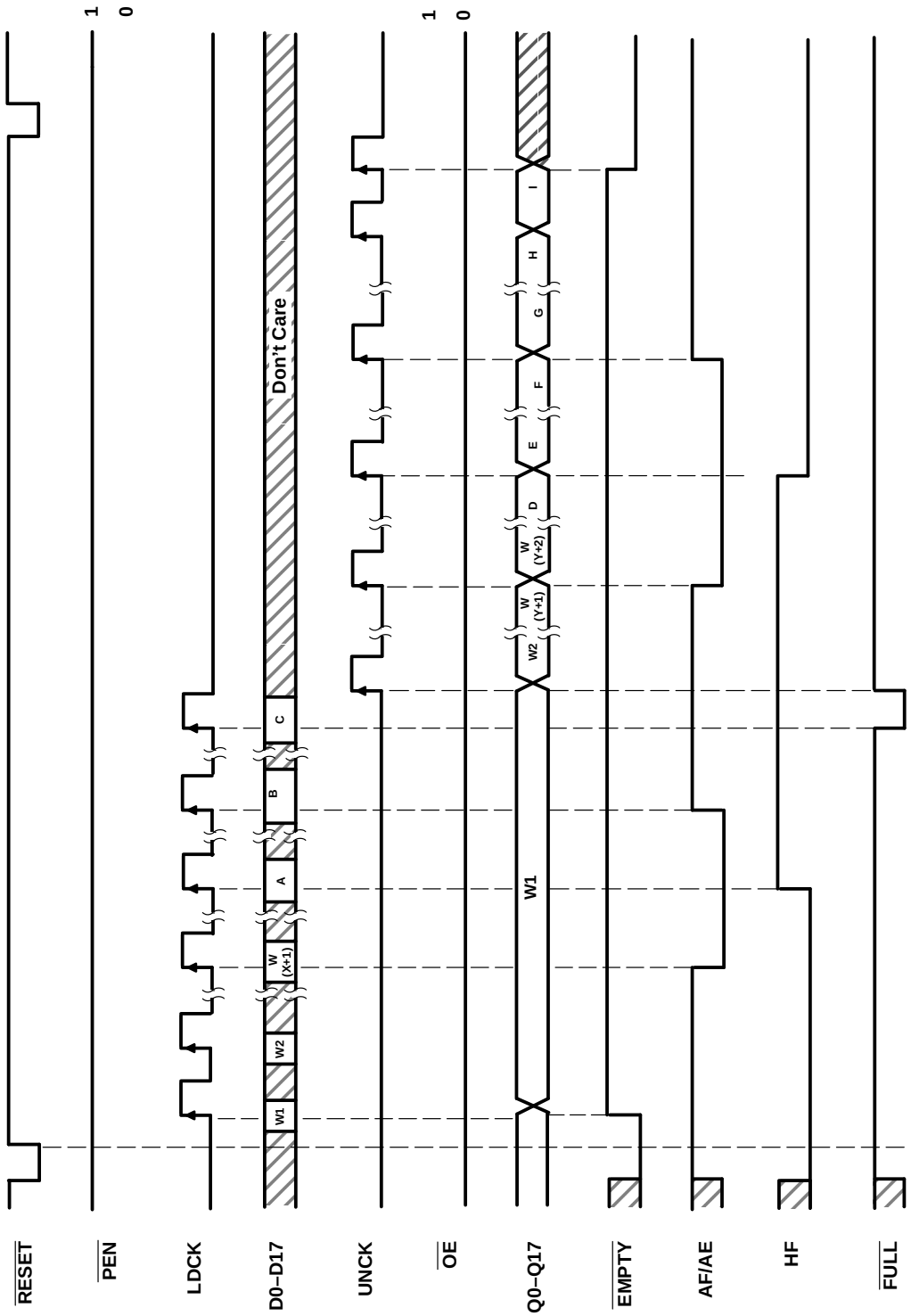

Figure 1. Write, Read, and Flag Timing Reference

DATA WORD NUMBERS FOR FLAG TRANSITIONS

DEVICE	TRANSITION WORD								
	A	B	C	D	E	F	G	H	I
SN74ALVC7814	W32	W(64 – Y)	W64	W33	W34	W(64 – X)	W(65 – X)	W64	W64

offset values for AF/AE

The AF/AE flag has two programmable limits: the almost-empty offset value (X) and the almost-full offset value (Y). They can be programmed after the FIFO is reset and before the first word is written to memory. The AF/AE flag is high when the FIFO contains X or fewer words or (64 minus Y) or more words.

To program the offset values, $\overline{\text{PEN}}$ can be brought low after reset. On the following low-to-high transition of LDCK, the binary value on D0 – D7 is stored as the almost-empty offset value (X) and the almost-full offset value (Y). Holding $\overline{\text{PEN}}$ low for another low-to-high transition of LDCK reprograms Y to the binary value on D0 – D4 at the time of the second LDCK low-to-high transition. Writes to the FIFO memory are disabled while the offsets are programmed. A maximum value of 31 can be programmed for either X or Y (see Figure 2). To use the default values of X = Y = 8, $\overline{\text{PEN}}$ must be held high.

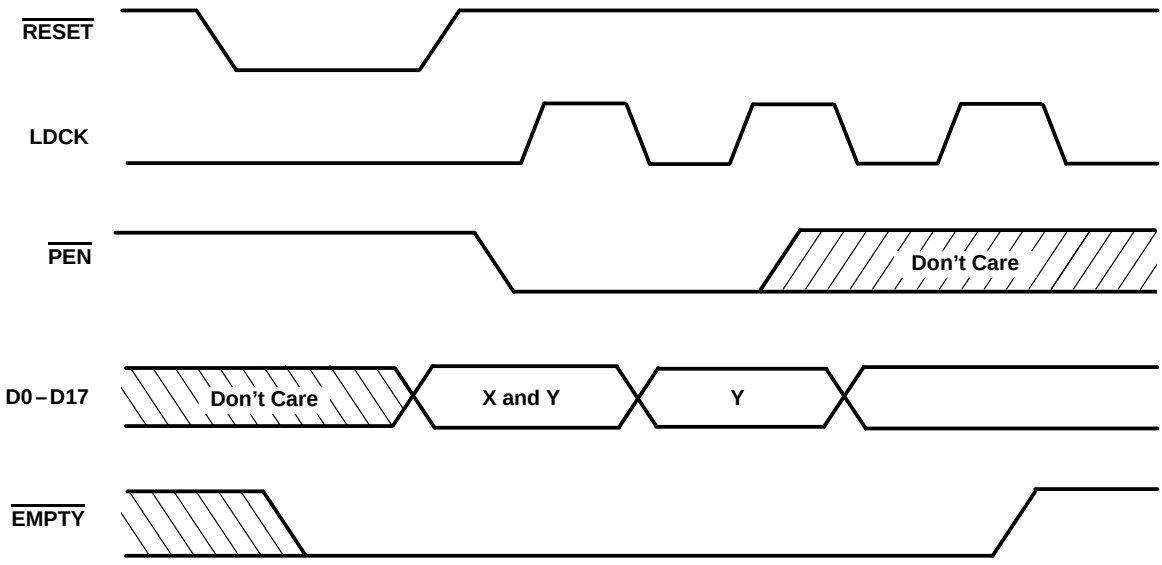

Figure 2. Programming X and Y Separately

PRODUCT PREVIEW

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC} . . . . . –0.5 V to 4.6 V
Input voltage range, V_I (see Note 1) . . . . . –0.5 V to 4.6 V
Output voltage range, V_O (see Notes 1 and 2) . . . . . –0.5 V to V_{CC} + 0.5 V
Input clamp current, I_{IK} (V_I < 0) . . . . . –50 mA
Output clamp current, I_{OK} (V_O < 0 or V_O > V_{CC}) . . . . . ±50 mA
Continuous output current, I_O (V_O = 0 to V_{CC}) . . . . . ±50 mA
Continuous current through V_{CC} or GND . . . . . ±100 mA
Voltage applied to a disabled 3-state output . . . . . 3.6 V
Operating free-air temperature range, T_A . . . . . 0°C to 70°C
Storage temperature range . . . . . –65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings can be exceeded if the input and output clamp current ratings are observed.
2. This value is limited to 4.6 V maximum.

recommended operating conditions

			’ALVC7814-25 V_{CC} = 3.3 V ± 0.3 V		’ALVC7814-40 V_{CC} = 3.3 V ± 0.3 V		UNIT
			MIN	MAX	MIN	MAX	
V_{IH}	High-level input voltage		2		2		V
V_{IL}	Low-level input voltage			0.8		0.8	V
V_I			0	V_{CC}	0	V_{CC}	V
V_O			0	V_{CC}	0	V_{CC}	V
I_{OH}	High-level output current, Q outputs, Flags	V_{CC} = 3 V		–8		–8	mA
I_{OL}	Low-level output current, Q outputs, Flags	V_{CC} = 3 V		16		16	mA
f_{clock}	Clock frequency			40		25	MHz
t_w	Pulse duration	D0–D17 high or low	8		12		ns
		LDCK high or low	8		12		
		UNCK high or low	8		12		
		$\overline{PEN}$ low	8		12		
		$\overline{RESET}$ low	10		12		
t_{su}	Setup time	D0–D17 before LDCK↑	5		5		ns
		LDCK inactive before $\overline{RESET}$ high	6		6		
		$\overline{PEN}$ before LDCK↑	8		8		
t_h	Hold time	D0–D17 after LDCK↑	0		0		ns
		$\overline{PEN}$ high after LDCK low	0		0		
		$\overline{PEN}$ low after LDCK↑	3		3		
		LDCK inactive after $\overline{RESET}$ high	6		6		
T_A	Operating free-air temperature		0	70	0	70	°C

PRODUCT PREVIEW

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS†		MIN	TYP‡	MAX	UNIT
V_{OH}	Flags, Q outputs	V_{CC} = MIN to MAX,	I_{OH} = – 100 µA	V_{CC} – 0.2			V
		V_{CC} = 3 V,	I_{OH} = – 8 mA	2.4			
V_{OL}	Flags, Q outputs	V_{CC} = MIN to MAX,	I_{OL} = 100 µA			0.2	V
	Flags	V_{CC} = 3 V,	I_{OL} = 8 mA			0.4	
	Q outputs	V_{CC} = 3 V,	I_{OL} = 16 mA			0.55	
I_I		V_{CC} = 3.6 V,	V_I = V_{CC} or GND			±5	µA
I_{OZ}		V_{CC} = 3.6 V,	V_O = V_{CC} or GND			±10	µA
I_{CC}		V_{CC} = 3.6 V,	V_I = V_{CC} or GND and I_O = 0			40	µA
ΔI_{CC}§		V_{CC} = 3.6 V, Other inputs at V_{CC} or GND	One input at V_{CC} – 0.6 V,			500	µA
C_i		V_{CC} = 3.3 V,	V_I = V_{CC} or GND		3		pF
C_o		V_{CC} = 3.3 V,	V_O = V_{CC} or GND		6		pF

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
‡ All typical values are at V_{CC} = 3.3 V, T_A = 25°C.
§ This is the supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 5)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	'ALVC7814-25 V_{CC} = 3.3 V ± 0.3 V		'ALVC7814-40 V_{CC} = 3.3 V ± 0.3 V		UNIT
			MIN	MAX	MIN	MAX	
f_{max}	LDCK or UNCK		40		25		MHz
t_{pd}	LDCK↑	Any Q	9	22	9	24	ns
t_{pd}	UNCK↑		6	18	6	20	
t_{PLH}	LDCK↑	$\overline{EMPTY}$	6	17	6	19	ns
t_{PHL}	UNCK↑		6	17	6	19	
t_{PHL}	$\overline{RESET}$ low		4	18	4	20	
t_{PHL}	LDCK↑	$\overline{FULL}$	6	17	6	19	ns
t_{PLH}	UNCK↑		6	17	6	19	
t_{PLH}	$\overline{RESET}$ low		4	20	4	22	
t_{pd}	LDCK↑	AF/AE	7	20	7	22	ns
t_{pd}	UNCK↑		7	20	7	22	
t_{PLH}	$\overline{RESET}$ low		2	12	2	14	
t_{PLH}	LDCK↑	HF	5	20	5	22	ns
t_{PHL}	UNCK↑		7	20	7	22	
t_{PHL}	$\overline{RESET}$ low		3	14	3	16	
t_{en}	$\overline{OE}$	Any Q	2	10	2	11	ns
t_{dis}			2	11	2	12	

operating characteristics, V_{CC} = 3.3 V, T_A = 25°C

PARAMETER			TEST CONDITIONS		TYP	UNIT
C_{pd}	Power dissipation capacitance per FIFO channel	Outputs enabled	C_L = 50 pF,	f = 5 MHz	53	pF

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APPLICATION INFORMATION

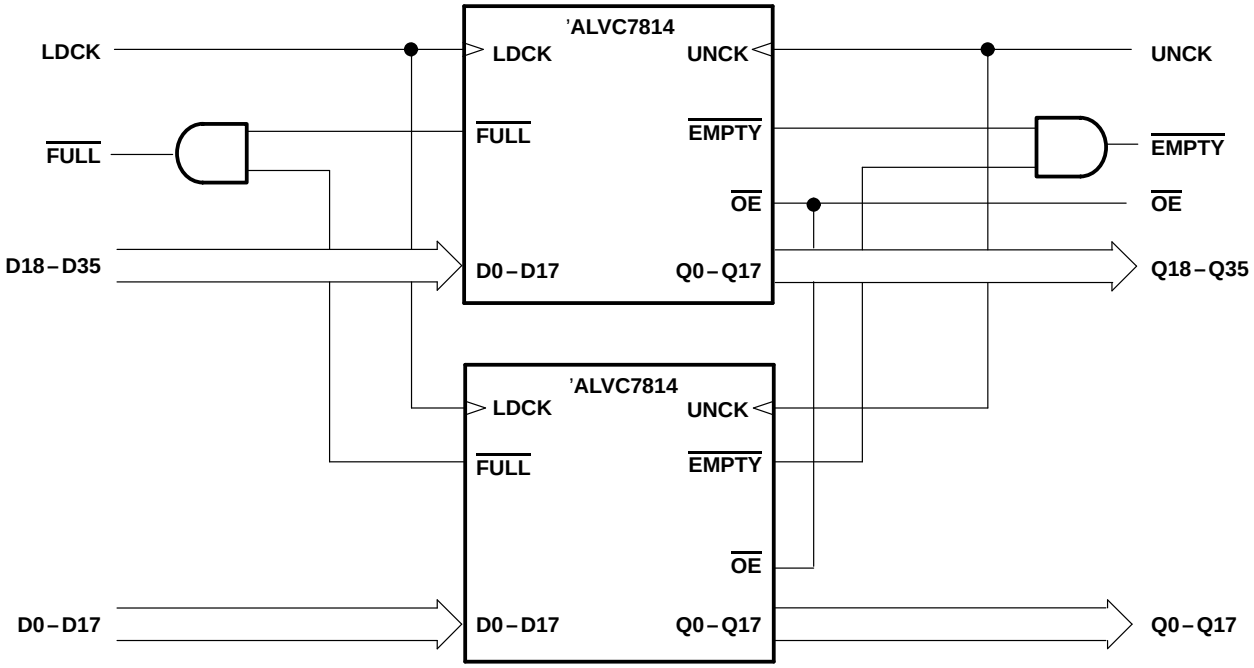

Figure 3. Word-Width Expansion: 64 × 36 Bit

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TYPICAL CHARACTERISTICS

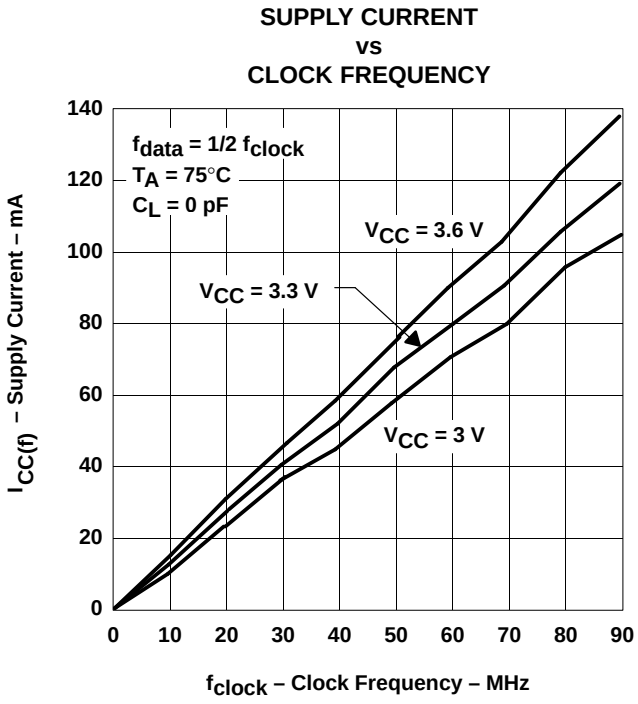


Figure 4

calculating power dissipation

With $I_{CC(f)}$ taken from Figure 4, the dynamic power (P_d), based on all data outputs changing states on each read, can be calculated by using:

$$P_d = V_{CC} \times [I_{CCf} + (N \times \Delta I_{CC} \times dc)] + \Sigma(C_L \times V_{CC}^2 \times f_o)$$

A more accurate total power (P_T) can be calculated if quiescent power (Pq) is also taken into consideration. Quiescent power (P_q) can be calculated using:

$$P_q = V_{CC} \times [I_{CCI} + (N \times \Delta I_{CC} \times dc)]$$

Total power will be:

$$P_T = P_d + P_q$$

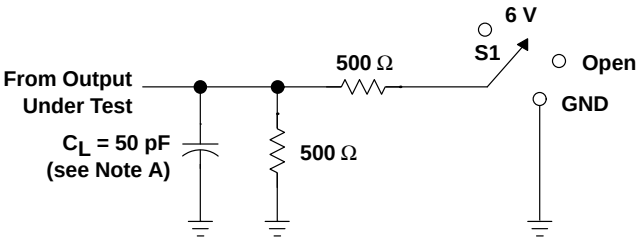
The above equations provide worst-case power calculations.

Where:

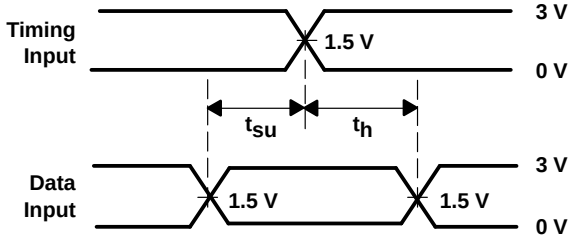
N	=	number of inputs driven by TTL levels
ΔI_{CC}	=	increase in power supply current for each input at a TTL high level
dc	=	duty cycle of inputs at a TTL high level of 3.4 V
C_L	=	output capacitance load
f_o	=	switching frequency of an output
I_{CCI}	=	idle current, supply current when FIFO is idle ≈ pF × f_{clock} = 0.2 × f_{clock} (current is due to free-running clocks)
pF	=	power factor (the slope of idle I_{CC} versus clock frequency)
I_{CCf}	=	active current, supply current when FIFO is transferring data

PRODUCT PREVIEW

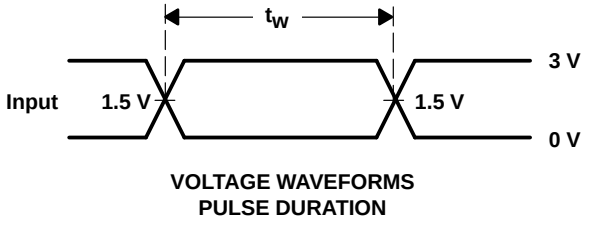
PARAMETER MEASUREMENT INFORMATION



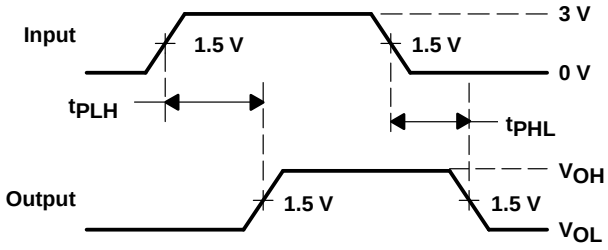
LOAD CIRCUIT FOR OUTPUTS



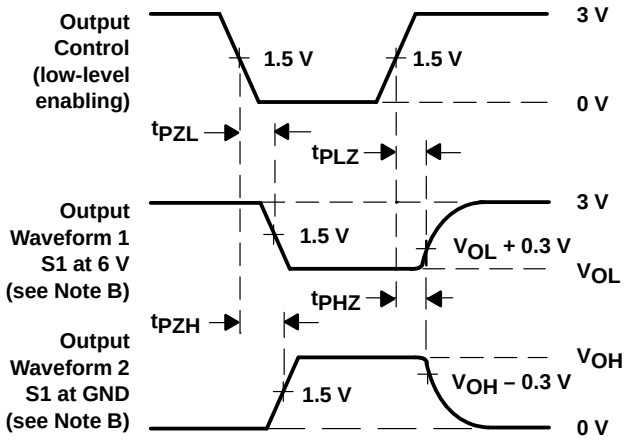
VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, t_r ≤ 2.5 ns, t_f ≤ 2.5 ns.

3-STATE OUTPUTS (ANY Q)

PARAMETER		R1, R2	C_L†	S1
t_{en}	t_{PZH}	500 Ω	50 pF	GND
	t_{PZL}			6 V
t_{dis}	t_{PHZ}	500 Ω	50 pF	GND
	t_{PLZ}			6 V
t_{pd}	t_{PLH}/t_{PHL}	500 Ω	50 pF	Open

† Includes probe and test-fixture capacitance

Figure 5. Standard CMOS Outputs (FULL, EMPTY, HF, AF/AE)

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